



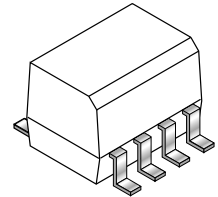
THE DATASHEET OF MOC223R1M



MOC223-M

DESCRIPTION

The MOC223-M consists of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon photodarlington detector, in a surface mountable, small outline, plastic package. It is ideally suited for high density applications, and eliminates the need for through - the - board mounting.

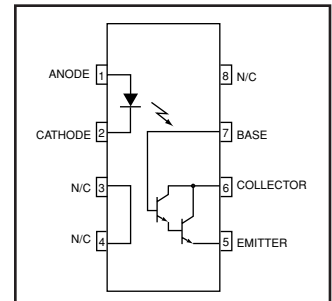


FEATURES

- U.L. Recognized (File #E90700, Volume 2)
- VDE Recognized (File #136616) (add option "V" for VDE approval, i.e, MOC223V-M)
- Industry Standard SOIC-8 Surface Mountable Package with 0.050" lead spacing
- High Current Transfer Ratio of 500% Minimum at $I_F = 1 \text{ mA}$
- Standard SOIC-8 Footprint, with 0.050" Lead Spacing
- Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering
- High Input-Output Isolation Voltage of 2500 $V_{AC(rms)}$ Guaranteed

APPLICATIONS

- Low Power Logic Circuits
- Interfacing and coupling systems of different potentials and impedances
- Telecommunications equipment
- Portable electronics
- Solid state relays



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless otherwise specified)			
Rating	Symbol	Value	Unit
EMITTER			
Forward Current - Continuous	I_F	60	mA
Forward Current - Peak (PW = 100 μs , 120 pps)	$I_F (pk)$	1.0	A
Reverse Voltage	V_R	6.0	V
LED Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	90 0.8	mW mW/ $^\circ\text{C}$
DETECTOR			
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Collector Voltage	V_{ECO}	7.0	V
Collector-Base Voltage	V_{CBO}	70	V
Collector Current-Continuous	I_C	150	mA
Detector Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	150 1.76	mW mW/ $^\circ\text{C}$
TOTAL DEVICE			
Input-Output Isolation Voltage (f = 60 Hz, t = 1 min.)	V_{ISO}	2500	Vac(rms)
Total Device Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	250 2.94	mW mW/ $^\circ\text{C}$
Ambient Operating Temperature Range	T_A	-40 to +100	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-40 to +150	$^\circ\text{C}$

MOC223-M

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)						
Parameter	Test Conditions	Symbol	Min	Typ*	Max	Unit
EMITTER						
Input Forward Voltage	($I_F = 1.0\text{ mA}$)	V_F	—	1.08	1.3	V
Reverse Leakage Current	($V_R = 6.0\text{ V}$)	I_R	—	0.001	100	μA
Input Capacitance		C_{IN}	—	18	—	pF
DETECTOR						
Collector-Emitter Dark Current	($V_{CE} = 5.0\text{ V}, T_A = 25^\circ\text{C}$)	I_{CEO1}	—	1.0	50	nA
	($V_{CE} = 5.0\text{ V}, T_A = 100^\circ\text{C}$)	I_{CEO2}	—	10	—	μA
Collector-Emitter Breakdown Voltage	($I_C = 100\ \mu\text{A}$)	BV_{CEO}	30	100	—	V
Emitter-Collector Breakdown Voltage	($I_E = 100\ \mu\text{A}$)	BV_{ECO}	7.0	10	—	V
Collector-Emitter Capacitance	($f = 1.0\text{ MHz}, V_{CE} = 0$)	C_{CE}	—	5.5	—	pF
COUPLED						
Current Transfer Ratio ⁽³⁾	($I_F = 1.0\text{ mA}, V_{CE} = 5.0\text{ V}$)	CTR	500	1000	—	%
Isolation Surge Voltage ^(1,2)	($f = 60\text{ Hz AC Peak}, t = 1\text{ min.}$)	V_{ISO}	2500	—	—	Vac(rms)
Isolation Resistance ⁽²⁾	($V = 500\text{ V}$)	R_{ISO}	10^{11}	—	—	Ω
Collector-Emitter Saturation Voltage	($I_C = 500\ \mu\text{A}, I_F = 1.0\text{ mA}$)	$V_{CE(sat)}$	—	—	1.0	V
Isolation Capacitance ⁽²⁾	($V_{I-O} = 0\text{ V}, f = 1\text{ MHz}$)	C_{ISO}	—	0.2	—	pF
Turn-On Time	(fig. 6)($I_F = 5.0\text{ mA}, V_{CC} = 10\text{ V}, R_L = 100\ \Omega$)	t_{on}	—	3.5	—	μs
Turn-Off Time	(fig. 6)($I_F = 5.0\text{ mA}, V_{CC} = 10\text{ V}, R_L = 100\ \Omega$)	t_{off}	—	95	—	μs
Rise Time	(fig. 6)($I_F = 5.0\text{ mA}, V_{CC} = 10\text{ V}, R_L = 100\ \Omega$)	t_r	—	1.0	—	μs
Fall Time	(fig. 6)($I_F = 5.0\text{ mA}, V_{CC} = 10\text{ V}, R_L = 100\ \Omega$)	t_f	—	2.0	—	μs

*All typicals at $T_A = 25^\circ\text{C}$

1. Isolation Surge Voltage, V_{ISO} , is an internal device dielectric breakdown rating.
2. For this test, Pins 1 and 2 are common and Pins 5, 6 and 7 are common.
3. Current Transfer Ratio (CTR) = $I_C/I_F \times 100\%$.

Fig. 1 LED Forward Voltage vs. Forward Current

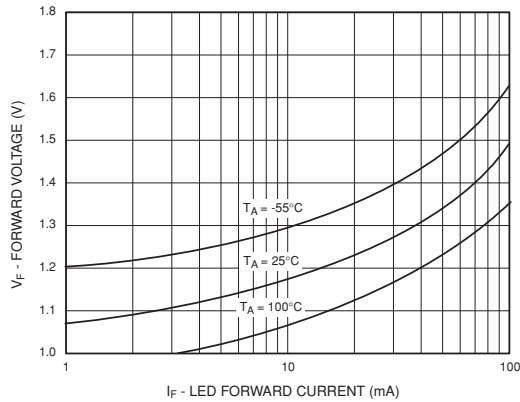


Fig. 2 Output Current vs. Input Current

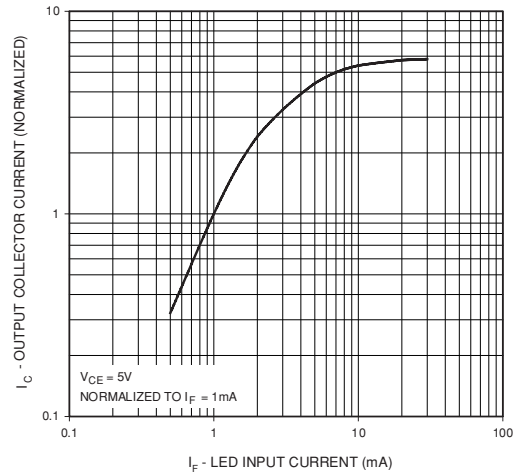


Fig. 3 Output Current vs. Ambient Temperature

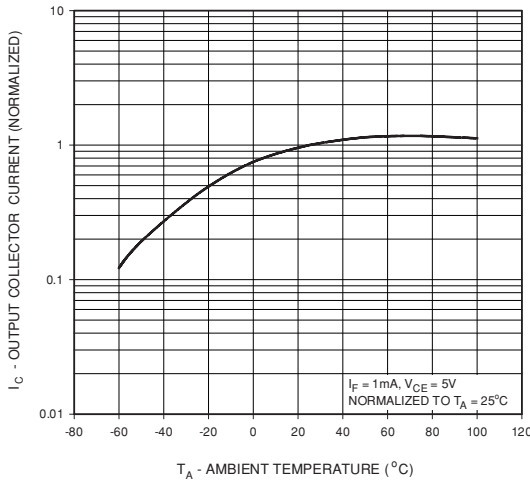


Fig. 4 Output Current vs. Collector - Emitter Voltage

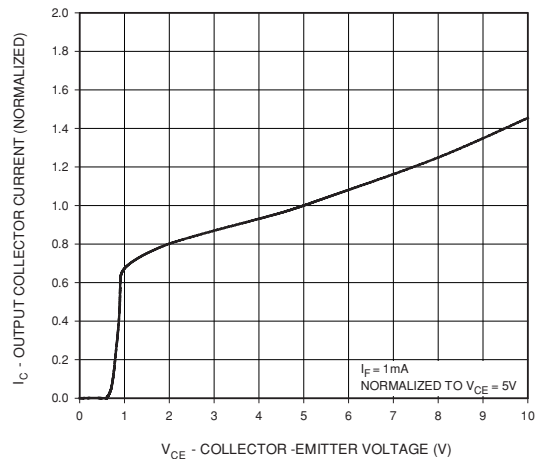
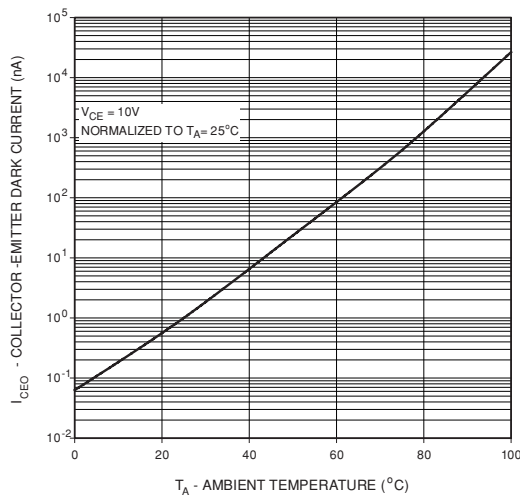


Fig. 5 Dark Current vs. Ambient Temperature



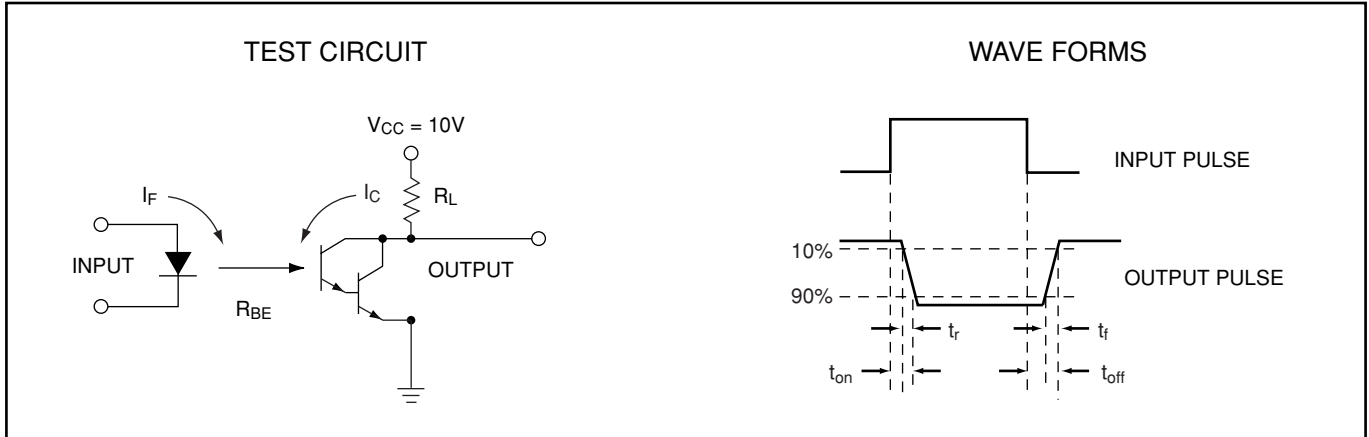
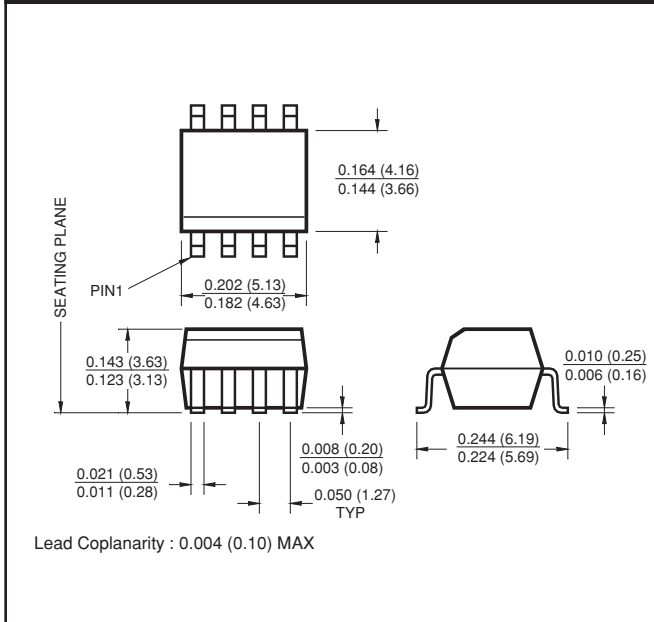
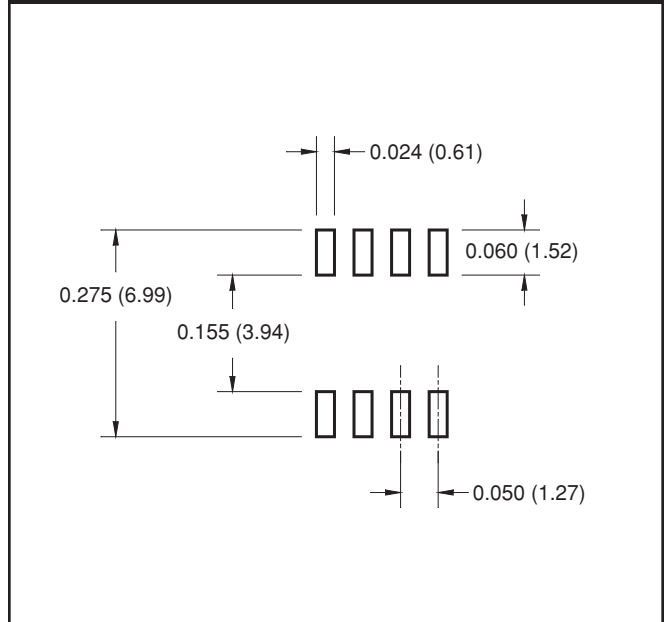


Figure 6. Switching Time Test Circuit and Waveforms

Package Dimensions (Surface Mount)



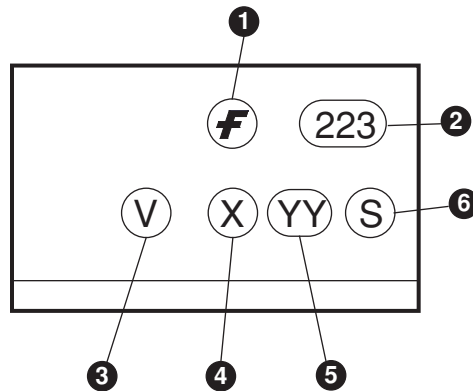
8-Pin Small Outline



ORDERING INFORMATION

Option	Order Entry Identifier	Description
V	V	VDE 0884
R1	R1	Tape and reel (500 units per reel)
R1V	R1V	VDE 0884, Tape and reel (500 units per reel)
R2	R2	Tape and reel (2500 units per reel)
R2V	R2V	VDE 0884, Tape and reel (2500 units per reel)

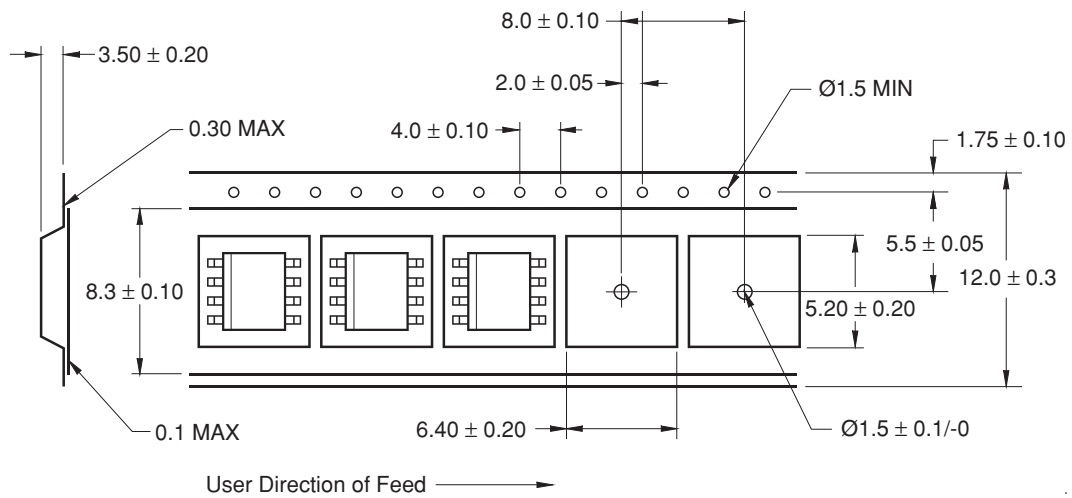
MARKING INFORMATION



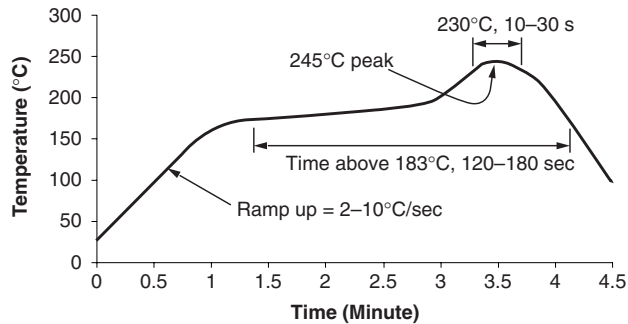
Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code, e.g., '3'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

*Note – 'V' option parts marked with date code '325' or earlier are marked in portrait format.

Carrier Tape Specifications



Reflow Profile



- Peak reflow temperature: 245°C (package surface temperature)
- Time of temperature higher than 183°C for 120–180 seconds
- One time soldering reflow is recommended

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